

## Description

The AH3241Q-AH3244Q/AH3280Q-AH3282Q are high-voltage, high-sensitivity, two-wire Hall-effect unipolar/latch switch ICs with integrated self-diagnostics and automotive-compliant AEC-Q100 qualification; designed for position and proximity sensing in automotive applications, such as seat and seatbelt buckle, transmission actuator, gear position, wiper, door/trunk closure, etc.

To support a wide range of demanding applications, the AH3241Q-AH3244Q/AH3280Q-AH3282Q are optimized to operate over a supply range of 2.7V to 27V. These features include a chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits. For robustness and protection, the device has built-in reverse blocking diode with a zener clamp on the supply.

The built-in thermal protection also shuts down the chip if temperature rises to an abnormal value. This will automatically restart the chip once the junction temperature drops below the safe value.

For AH3241Q, AH3242Q, AH3243Q, and AH3244Q 2-wire unipolar switches: when the flux density (south pole) exceeds  $B_{OP}$ , the supply current state is turned on (low or high). The output is held until a magnetic flux density falls below  $B_{RP}$ , causing output current to be turned off.

For AH3280Q, AH3281Q, and AH3282Q 2-wire latch switches: when the magnetic flux density is larger than  $B_{OP}$ , output current is turned on (high). The output state is held until a magnetic flux density reversal falls below  $B_{RP}$ , causing output current to be turned off (low).

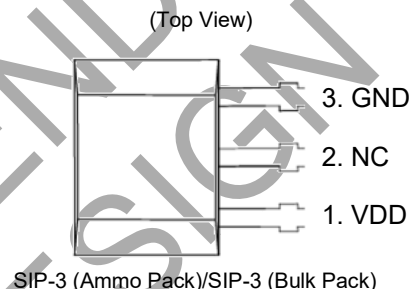
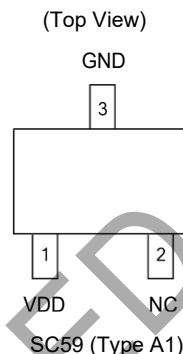
## Features and Performance

- Unipolar: AH3241Q, AH3242Q, AH3243Q, AH3244Q
- Latch: AH3280Q, AH3281Q, AH3282Q
- Output Polarity:
  - Direct: AH3242Q, AH3243Q
  - Inverted: AH3241Q, AH3244Q
- Wide Supply Voltage Operation: 2.7V to 27V
- Temperature Coefficient -1100ppm/°C (AH3242Q, AH3243Q, AH3244Q)
- Chopper Stabilized Design Provides:
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Battery Polarity Reverse Connection Protection
- Transient Spike Voltage Protection
- Overtemperature Shutdown and Auto-Restart
- UVLO Protection
- High ESD Rating: HBM = 8kV, CDM = 1kV
- Ready for ISO 26262
- Temperature Range: -40°C to +150°C
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1, 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The AH3241Q-AH3244Q/AH3280Q-AH3282Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

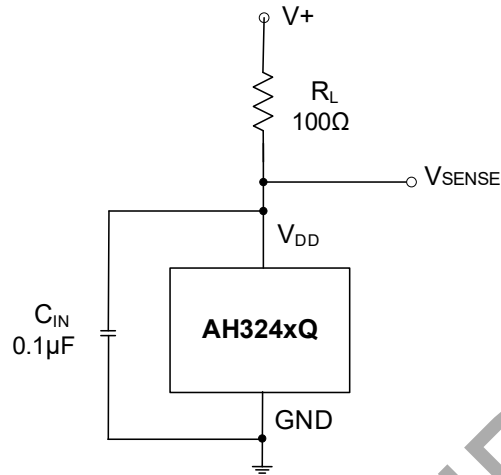
## Pin Assignments



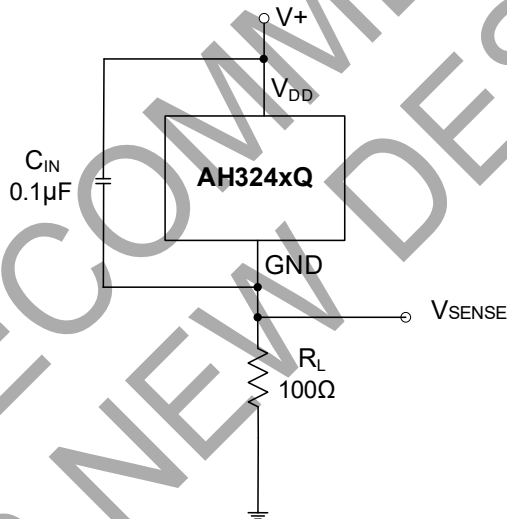
## Applications

- Position and proximity sensing in automotive applications
- Seat positioning
- Seatbelt buckles
- Wiper positioning
- Window lifters
- Gear selection positioning

## Typical Applications Circuit



(1) High-Side Sensing



(2) Low-Side Sensing

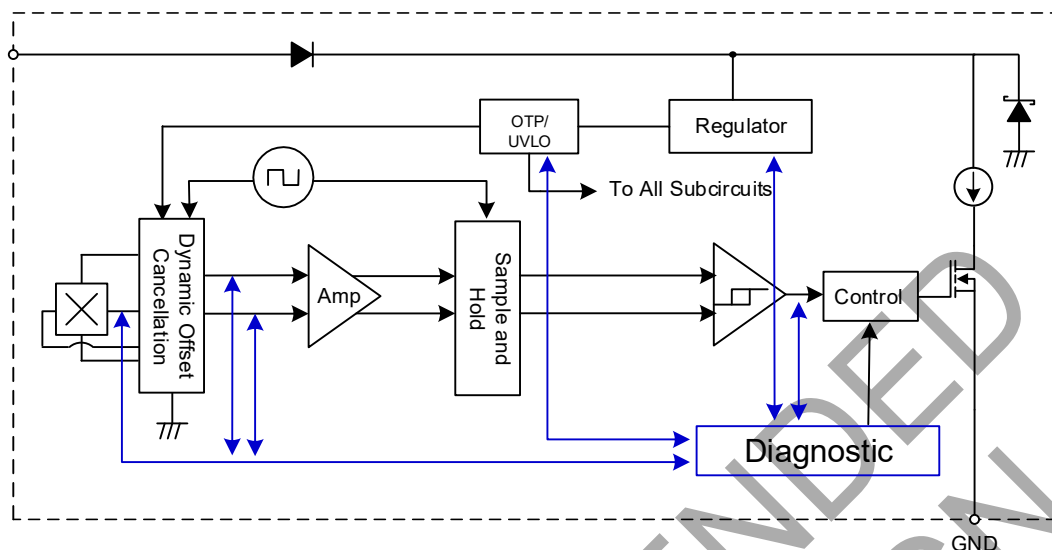
Note: 4. A 100nF or larger decoupling capacitor (CIN) between VDD and GND pins is needed for power stabilization and to strengthen noise immunity; CIN needs to be as close to IC as possible. Typical RL value is 100Ω. Larger or additional series resistor is recommended if there are disturbances on VDD.

## Pin Descriptions

Packages: SC59 (Type A1) and SIP-3 (Ammo Pack and Bulk Pack)

Pin Number	Pin Name	Function
1	VDD	Supply Voltage Input
2	NC	No connection; can be connected to VDD, GND, or left open.
3	GND	Ground

### Functional Block Diagram



**Absolute Maximum Ratings** (Note 5) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V <sub>DD</sub> (Note 6)	Supply Voltage	32	V
V <sub>DDR</sub> (Note 6)	Reverse Supply Voltage	-32	V
B	Magnetic Flux Density	Unlimited	Gauss
T <sub>J_MAX</sub>	Maximum Junction Temperature	+180	°C
T <sub>S</sub>	Storage Temperature	-55 to +180	°C
ESD (HBM)	ESD (Human Body Model)	8000	V
ESD (CDM)	ESD (Charged Device Model)	1000	V

Notes:

5. Stresses greater than those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to *Absolute Maximum Ratings* for extended periods can affect device reliability.
6. Should not be exceeded the maximum junction temperature and maximum duration of 500ms.

**Recommended Operating Conditions** (@  $T_A = -40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ ,  $T_J = -40^{\circ}\text{C}$  to  $+165^{\circ}\text{C}$ , unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V <sub>DD</sub>	Supply Voltage, between VDD and GND Pins	2.7	27	V
T <sub>OP</sub>	Operating Ambient Temperature	-40	+150	°C

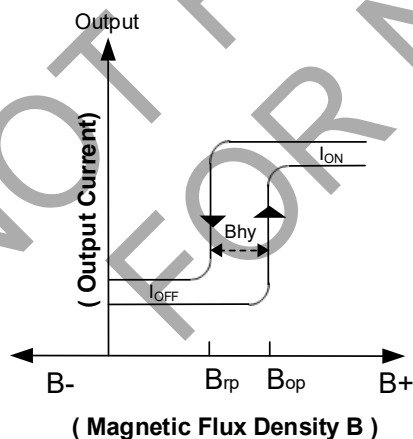
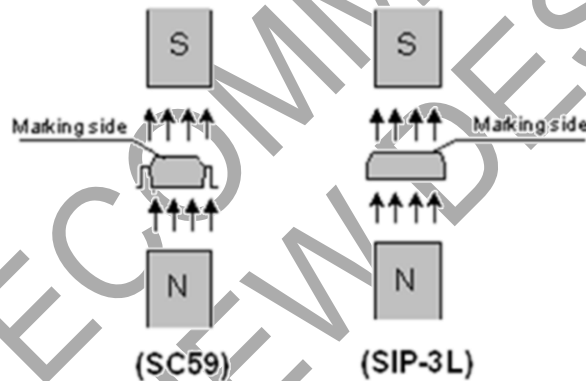
**Electrical Characteristics** (Note 7) (@  $T_A = -40^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ ,  $T_J = -40^{\circ}\text{C}$  to  $+165^{\circ}\text{C}$ ,  $V_{DD} = 2.7\text{V}$  to  $27\text{V}$ , unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DD}$	Supply Voltage (Note 8)	—	2.7	12	27	V
$I_{OFF(2)}$	Supply Current Off State	$V_{DD} = 2.7\text{V}$ to $27\text{V}$ (AH3280Q, AH3282Q)	2	3.3	5	mA
$I_{OFF(1)}$	Supply Current Off State	$V_{DD} = 2.7\text{V}$ to $27\text{V}$ (AH3241Q, AH3242Q, AH3243Q, AH3244Q, AH3281Q)	5	6	6.9	mA
$I_{ON}$	Supply Current On State	$V_{DD} = 2.7\text{V}$ to $27\text{V}$	12	14.5	17	mA
$V_{UVLO}$	Undervoltage Lockout Threshold	Voltage dropping	—	2.2	2.7	V
$t_{UVLO}$	Undervoltage Lockout Reaction Time	—	—	10	—	$\mu\text{s}$
$I_{DDR}$	Reverse Supply Current	$V_{DD} = -18\text{V}$ , $T = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$	-1.5	—	—	mA
$T_{TP}$	Thermal Protection Threshold	Junction temperature	—	190	—	$^{\circ}\text{C}$
$T_{TPR}$	Thermal Protection Release Threshold	Junction temperature	—	180	—	$^{\circ}\text{C}$
$f_M$	Maximum Magnet Switching Frequency	$B > 3 \cdot B_{OP}$ , alternative square magnet field	30	50	—	kHz
$f_C$	Chopping Frequency	—	—	1000	—	kHz
$I_{SAFE}$	Safe Mode Supply Current	Safe mode supply current / error current (mA)	0.5	1	1.5	mA
$t_{PON}$	Power-On Delay Time (Note 9)	$B > B_{OP} + 10\text{GS}$	—	28	40	$\mu\text{s}$
$t_D$	Response Delay Time (Note 10)	$B > 3 \cdot B_{OP}$	—	7	—	$\mu\text{s}$
$t_{RF}$	Current Rise/Fall Time	$V_{DD} = 12\text{V}$ , No bypass capacitor, $C_{LOAD} = 50\text{pF}$ to GND	0.1	0.3	1	$\mu\text{s}$
POS	Power-up State (Notes 9, 11)	$t > t_{PON(max)}$ , $V_{DD}$ slew rate $> 1\text{V}/\mu\text{s}$	—	$I_{OFF}$	—	—
—	Output Jitter	$B \geq 3 \cdot B_{OPMAX}$ 1000 successive square wave switching under 1kHz.	—	$\pm 3.3$	—	$\mu\text{s}$

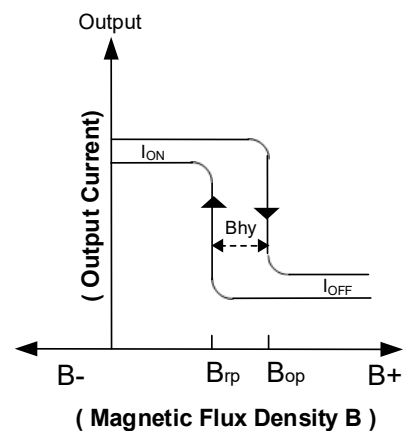
- Notes:
- Typical values are defined at  $T_A = +25^{\circ}\text{C}$ ,  $V_{DD} = 12\text{V}$ . Maximum and minimum values over the operating temperature range are not tested in production but guaranteed by design, process control and characterization.
  - $V_{DD}$  is the voltage between the VDD pin and the GND pin.
  - When power is initially turned on,  $V_{DD}$  must be operated in the correct voltage range to guarantee proper magnetic field sampling, output supply current state level is valid after the startup time of  $28\mu\text{s}$  from  $V_{DD}$  higher than  $2.7\text{V}$ . Guaranteed by design.
  - Time delayed from the magnetic threshold reached to the output rise or fall.
  - $t > t_{PON}$  and  $B_{RP} < B < B_{OP}$ .

**Magnetic Characteristics** (Notes 12, 13) ( $T_A = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ,  $T_J = -40^\circ\text{C}$  to  $+165^\circ\text{C}$ ,  $V_{DD} = 2.7\text{V}$  to  $27\text{V}$ , unless otherwise specified)

Part Name	Test Condition	Operating Point $B_{OP}$ (Gauss)			Release Point $B_{RP}$ (Gauss)			Temperature Coefficient (ppm/ $^\circ\text{C}$ )	$I_{OFF}$ (mA)	Active Pole	Output Polarity
		Min	Typ	Max	Min	Typ	Max	Typ	Typ		
AH3241Q	$T_A = +25^\circ\text{C}$	65	90	120	45	70	100	0	6	South	Inverted
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	55	90	135	35	70	115				
AH3242Q	$T_A = +25^\circ\text{C}$	40	60	80	20	40	60	-1100	6	South	Direct
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	30	60	90	10	40	70				
AH3243Q	$T_A = +25^\circ\text{C}$	27	45	63	10	28	46	-1100	6	South	Direct
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	20	45	70	3	28	53				
AH3244Q	$T_A = +25^\circ\text{C}$	27	45	63	10	28	46	-1100	6	South	Inverted
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	20	45	70	3	28	53				
AH3280Q	$T_A = +25^\circ\text{C}$	8	18	28	-28	-18	-8	0	3.3	South	Direct
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	3	18	33	-33	-18	-3				
AH3281Q	$T_A = +25^\circ\text{C}$	8	18	28	-28	-18	-8	0	6	South	Direct
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	3	18	33	-33	-18	-3				
AH3282Q	$T_A = +25^\circ\text{C}$	15	30	45	-45	-30	-15	0	3.3	South	Direct
	$T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$	10	30	50	-50	-30	-10				



1) Direct South Pole Active

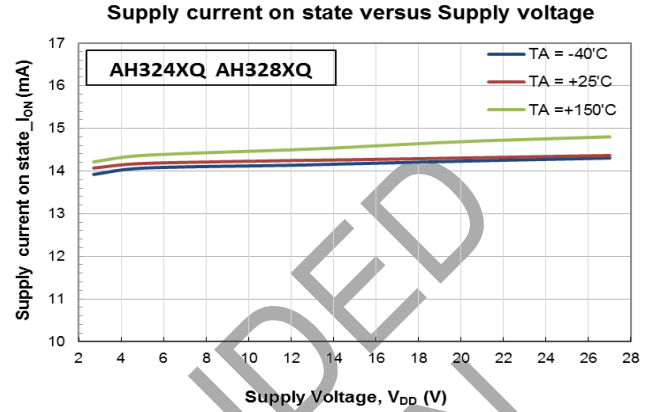
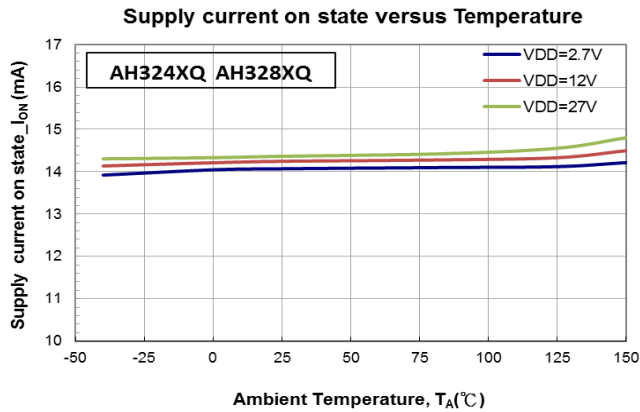


2) Inverted South Pole Active

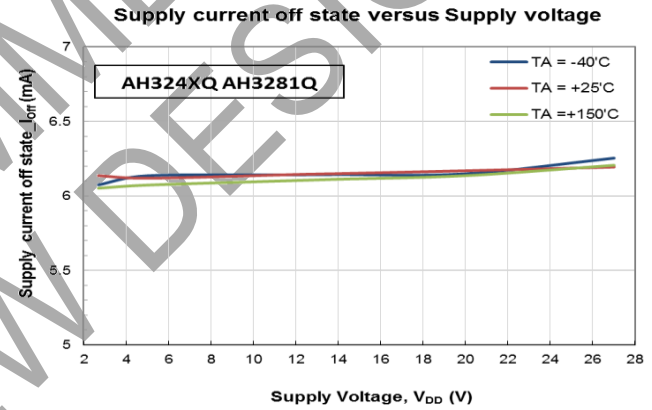
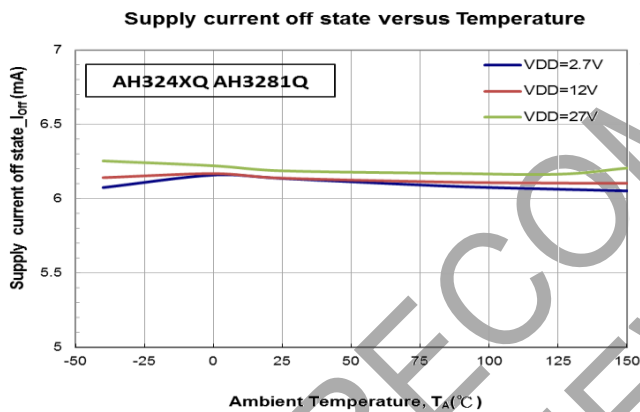
- Notes:
12. Positive x-axis direction indicates the South Pole approaching the part marking surface of SIP3 and SC59 i.e. increasing south pole magnetic field strength to the sensor; reversing direction x-axis toward 0 means the decreasing south magnetic field strength to the sensor. Negative x-axis indicates north pole magnetic field to the part marking surface.
  13. Typical values are defined at  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = 12\text{V}$ . Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

## Typical Operating Characteristics

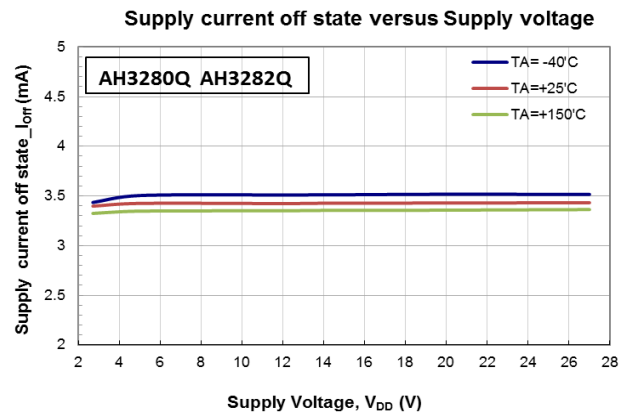
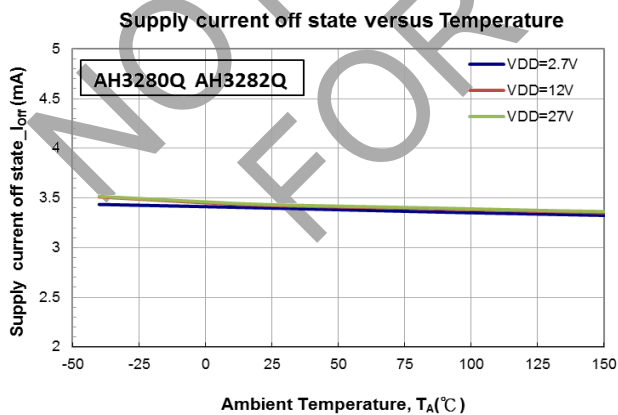
### AH324XQ\_AH328XQ Supply Current ON, $I_{ON}$ Performance



### AH324XQ\_AH3281Q Supply Current OFF, $I_{OFF(1)}$ Performance

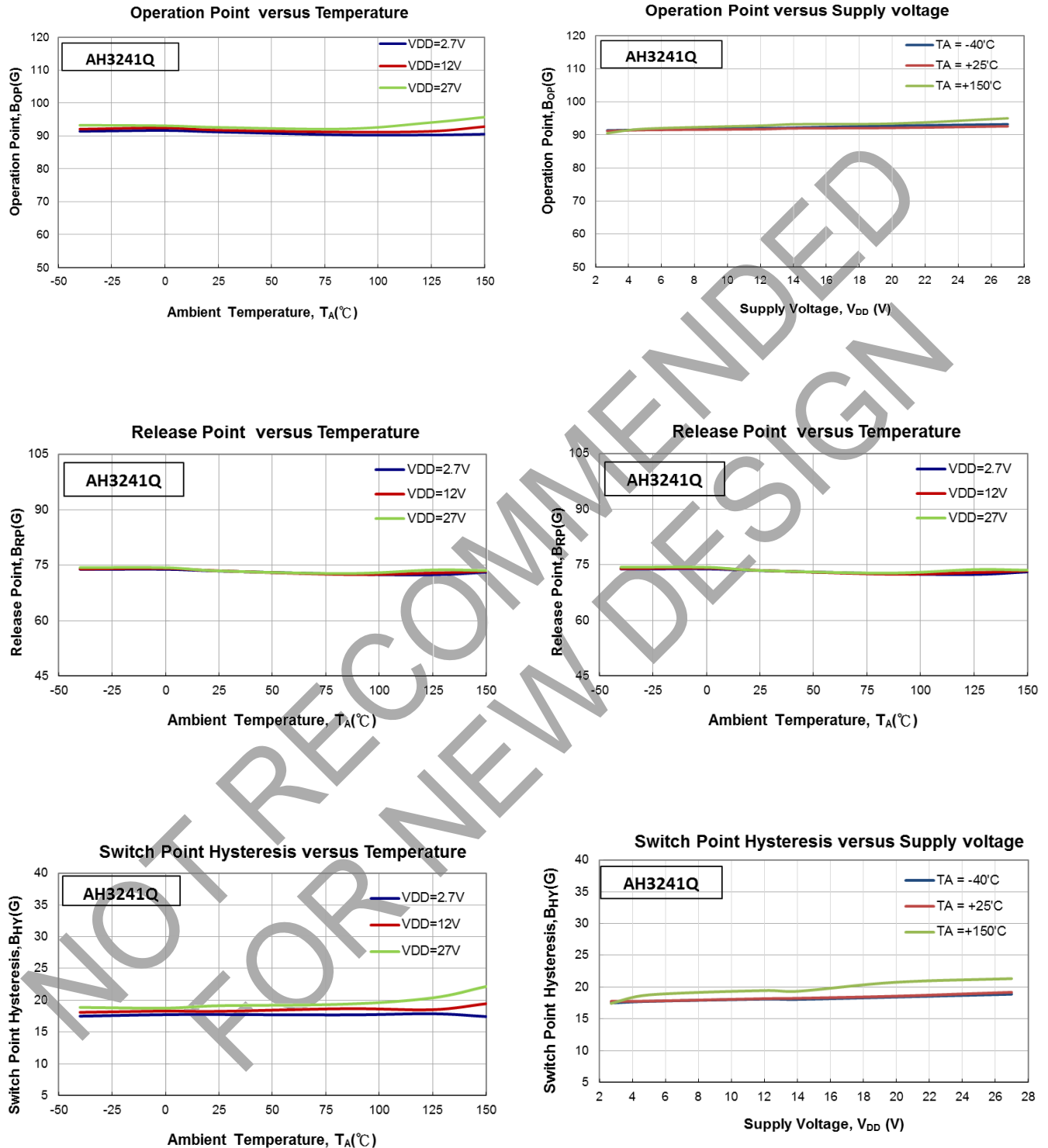


### AH3280Q\_AH3282Q Supply Current OFF, $I_{OFF(2)}$ Performance



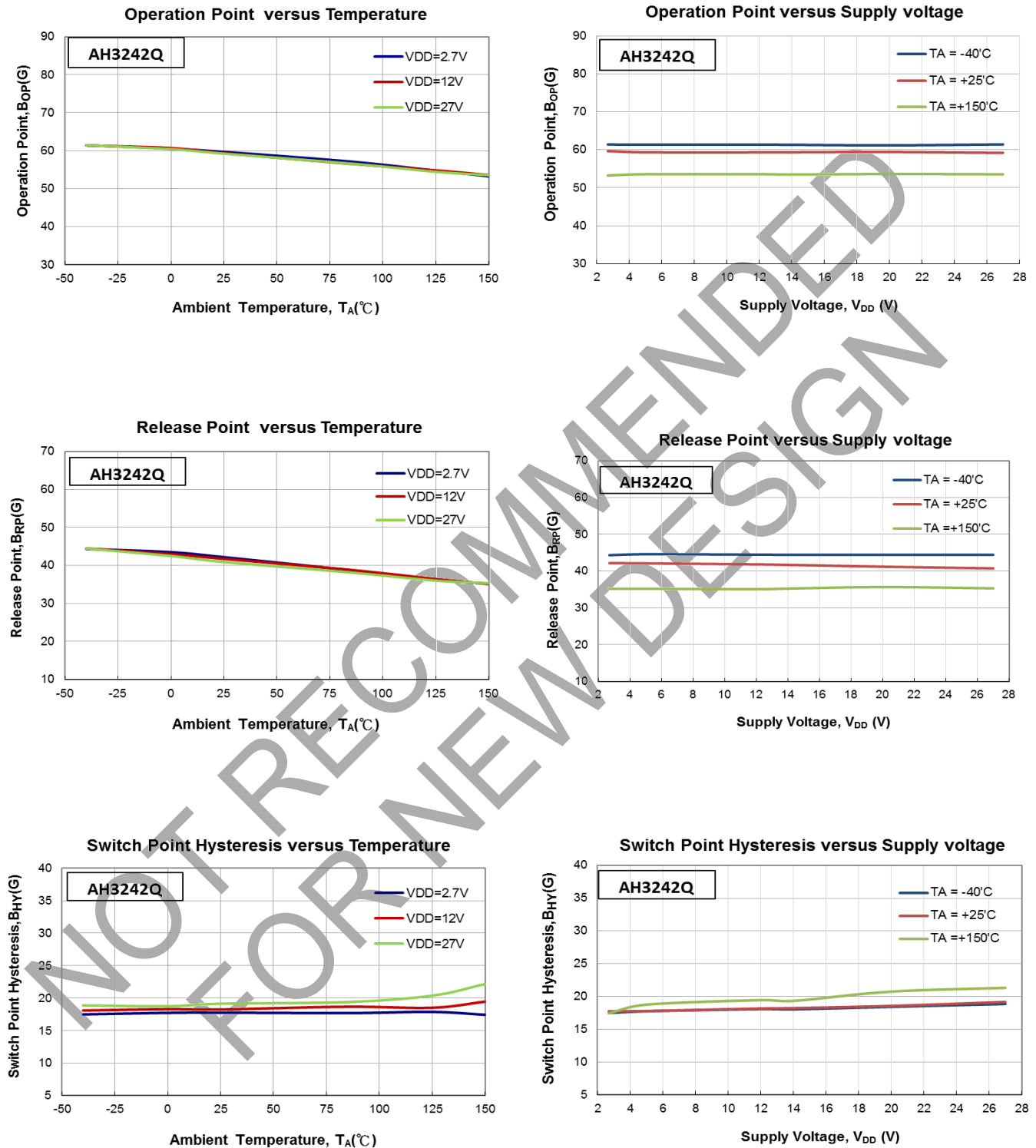
**Typical Operating Characteristics** (continued)

**AH3241Q Magnetic Characteristics Performance**



**Typical Operating Characteristics** (continued)

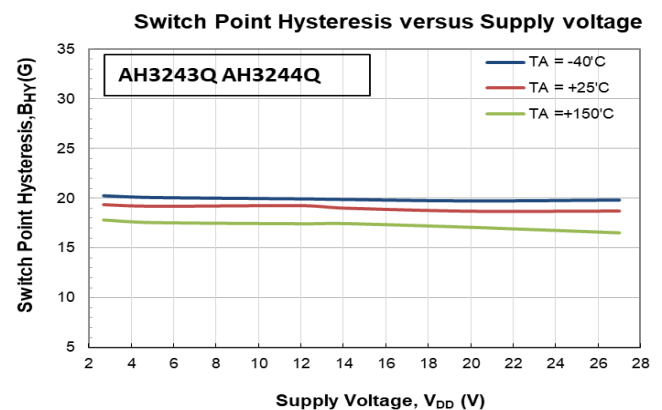
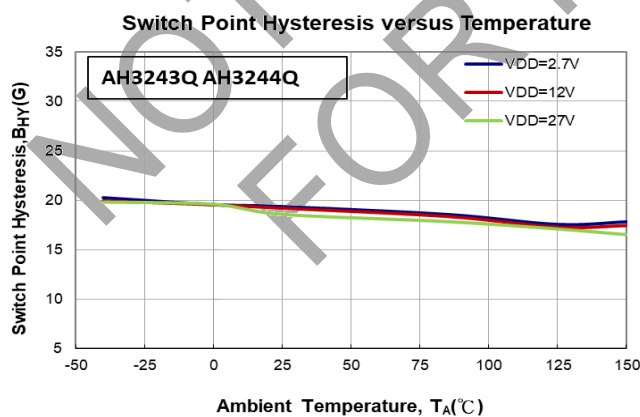
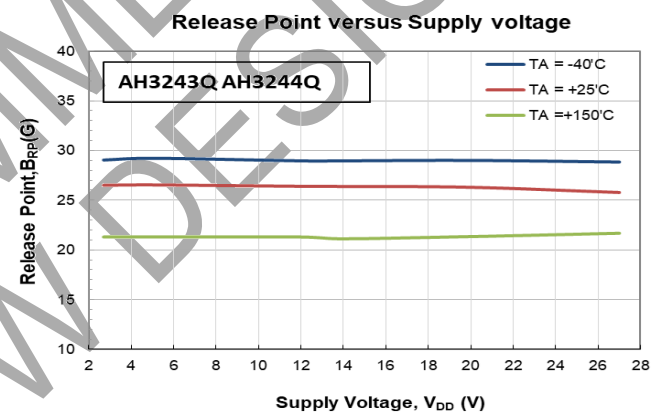
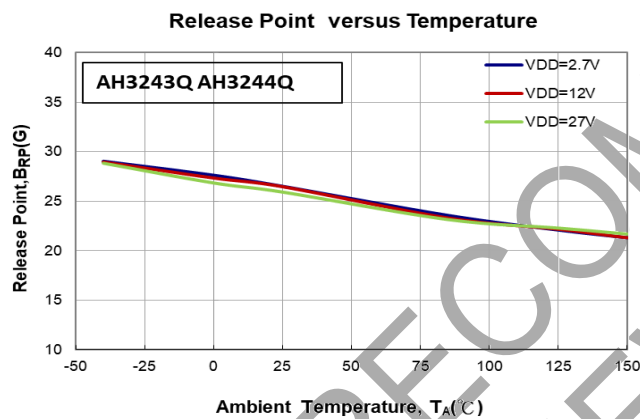
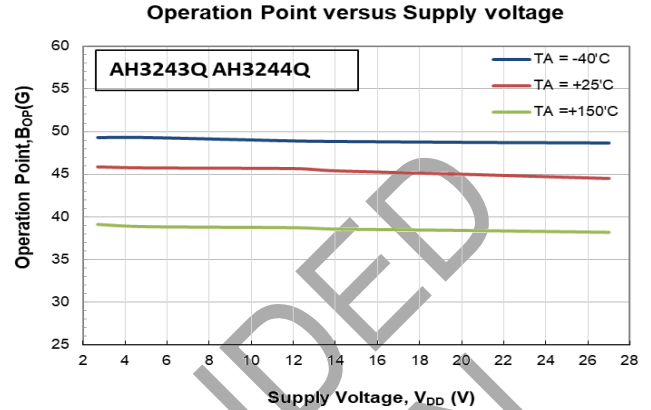
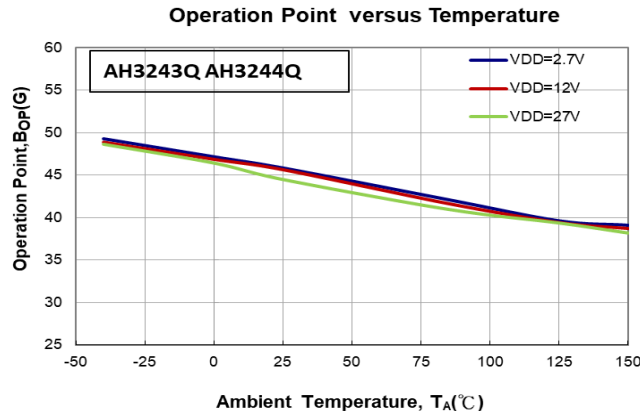
**AH3242Q Magnetic Characteristics Performance**





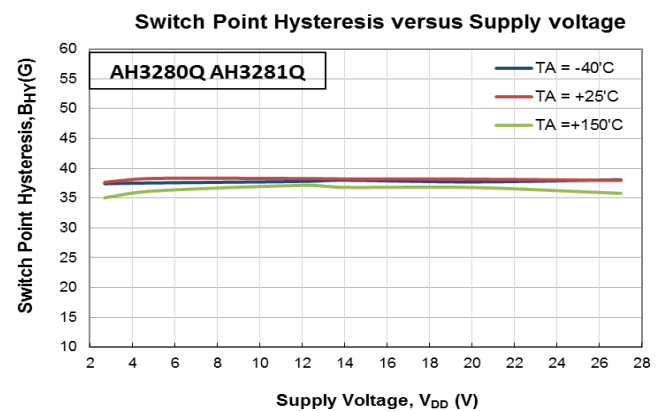
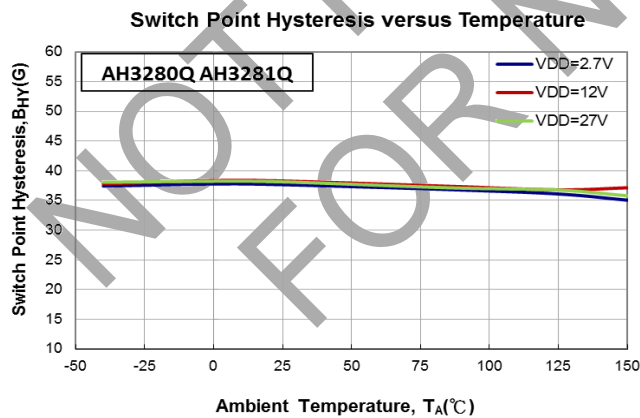
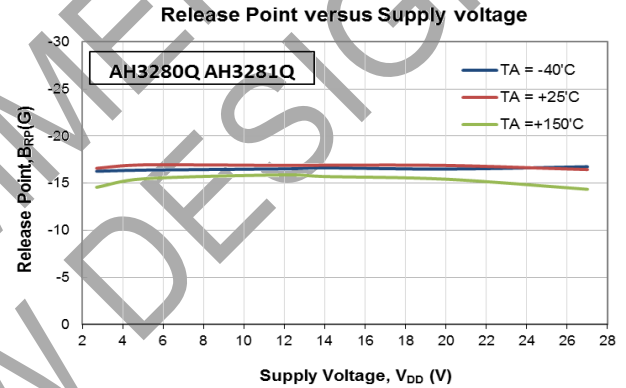
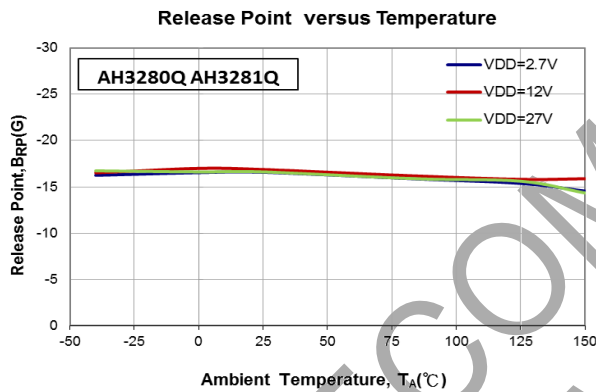
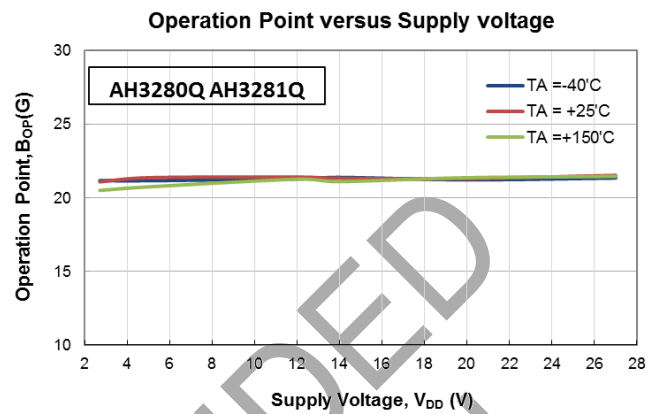
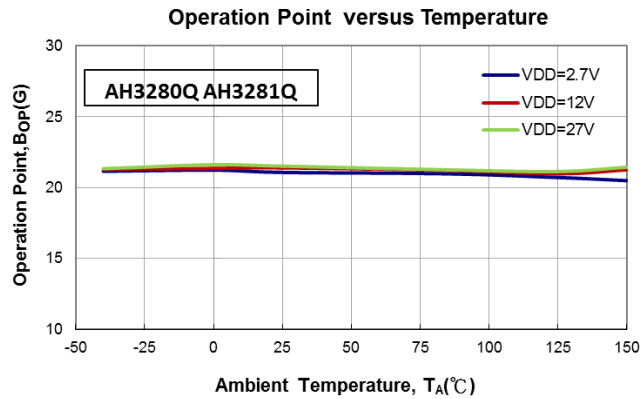
**Typical Operating Characteristics** (continued)

**AAH3243Q\_AH3244Q Magnetic Characteristics Performance**



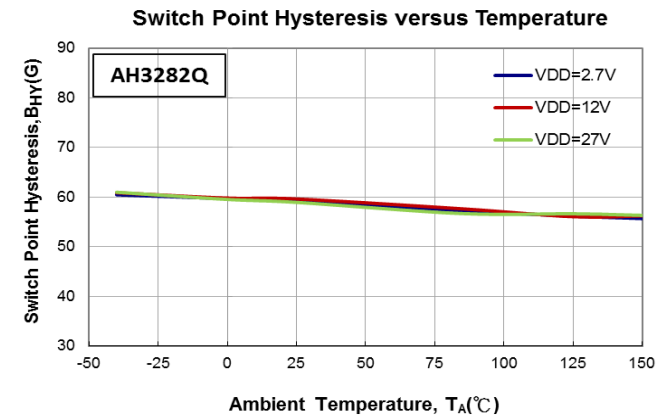
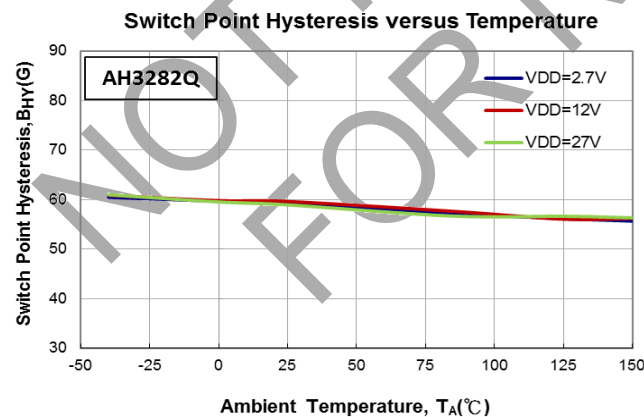
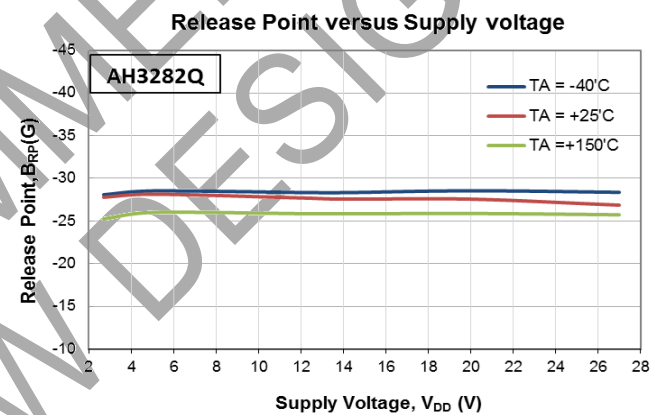
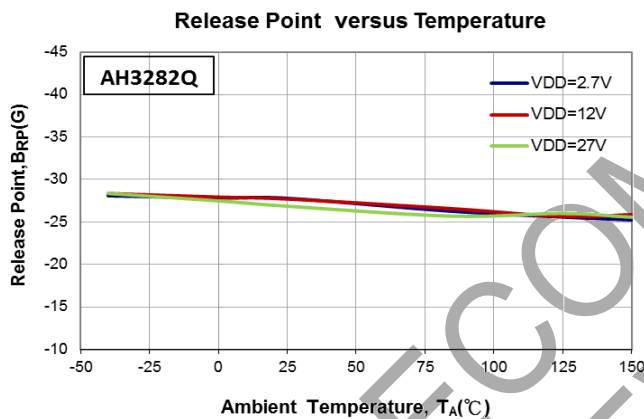
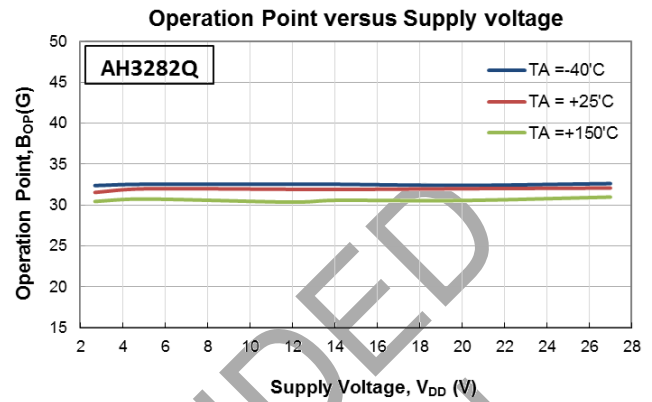
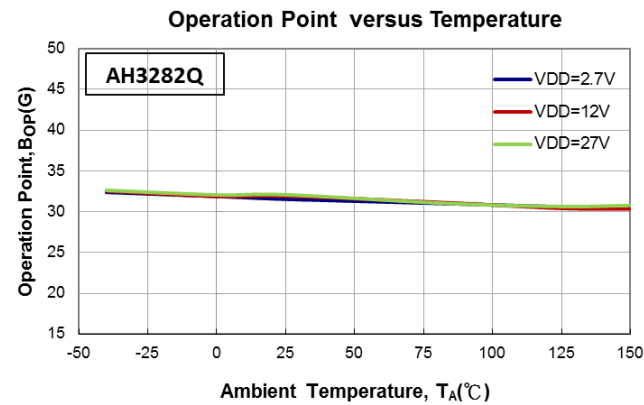
**Typical Operating Characteristics** (continued)

**AH3280Q\_AH3281Q Magnetic Characteristics Performance**



**Typical Operating Characteristics** (continued)

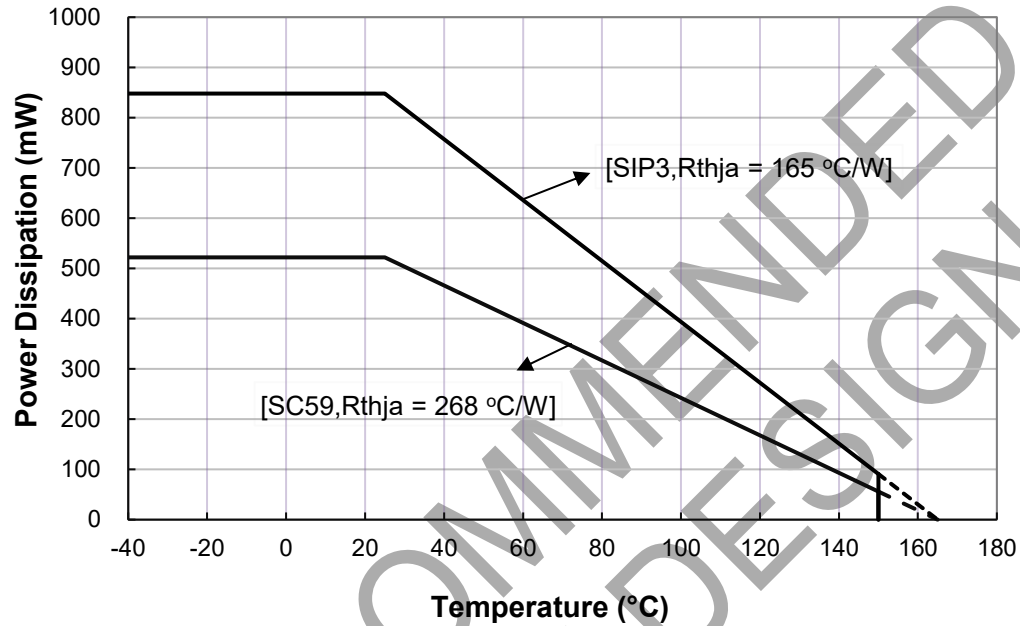
**AH3282Q Magnetic Characteristics Performance**



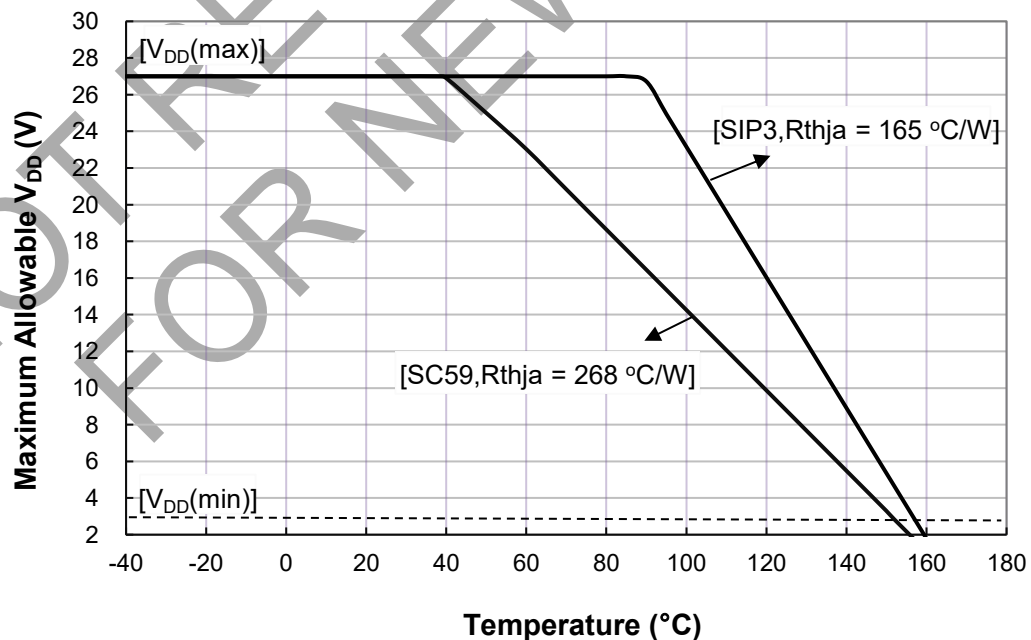
## Thermal Performance Characteristics

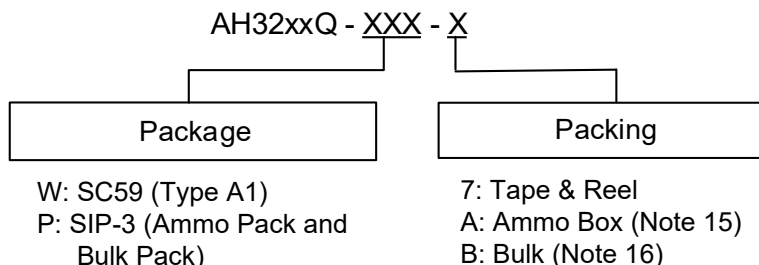
Symbol	Parameter	Conditions	Rating	Unit
R <sub>θJA</sub>	Package Thermal Resistance	SC59 (Type A1), 50mm*50mm 2oz MRB PCB, single layer	268	°C/W
		SIP-3 (Ammo Pack and Bulk Pack), 50mm*50mm 2oz MRB PCB, single layer	143	°C/W

### Thermal Derating Curve vs. Ambient Temperature



### Power Derating Curve



**Ordering Information** (Note 14)


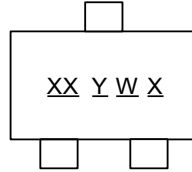
Orderable Part Number	Package Code	Package	Packing	
			Qty.	Carrier
AH3241Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3241Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3241Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3242Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3242Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3242Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3243Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3243Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3243Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3244Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3244Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3244Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3280Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3280Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3280Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3281Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3281Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk Box
AH3281Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel
AH3282Q-P-A	P	SIP-3 (Ammo Pack)	4000	Ammo Box
AH3282Q-P-B	P	SIP-3 (Bulk Pack)	1000	Bulk BOx
AH3282Q-W-7	W	SC59 (Type A1)	3000	Tape & Reel

Notes: 14. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.  
 15. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead.  
 16. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

## Marking Information

### (1) Package Type: SC59 (Type-A1)

(Top View)

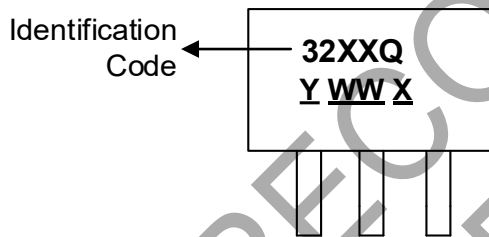


XX : Identification Code  
Y : Year 0 to 9 (ex: 5 = 2025)  
W : Week : A to Z : week 1 to 26;  
a to z : week 27 to 52; z represents  
week 52 and 53  
X : Internal Code

Orderable Part Number	Package	Identification Code
AH3241Q-W-7	SC59 (Type A1)	BR
AH3242Q-W-7	SC59 (Type A1)	BS
AH3243Q-W-7	SC59 (Type A1)	BT
AH3244Q-W-7	SC59 (Type A1)	BX
AH3280Q-W-7	SC59 (Type A1)	BW
AH3281Q-W-7	SC59 (Type A1)	BU
AH3282Q-W-7	SC59 (Type A1)	BV

### (2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

(Top View)



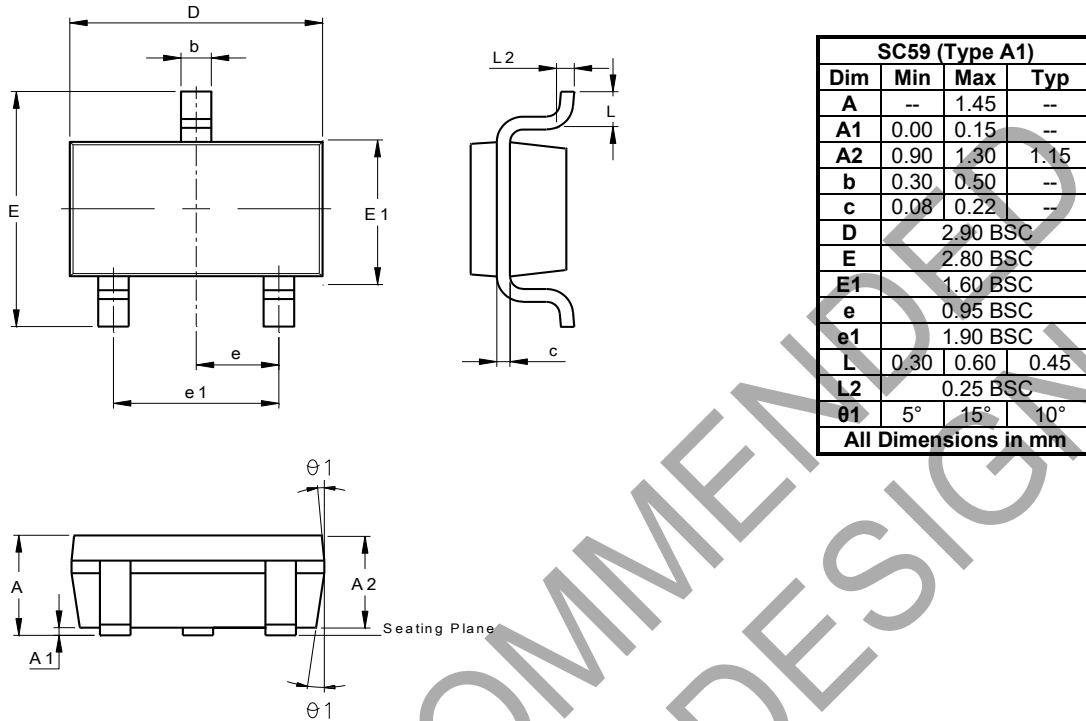
32XXQ : Identification Code  
Y : Year : 0 to 9 (ex: 5 = 2025)  
WW : Week : 01 to 52, "52" represents  
week 52 and 53  
X : Internal Code

Orderable Part Number	Package	Identification Code
AH3241Q-P-A	SIP-3 (Ammo Pack)	3241Q
AH3241Q-P-B	SIP-3 (Bulk Pack)	3241Q
AH3242Q-P-A	SIP-3 (Ammo Pack)	3242Q
AH3242Q-P-B	SIP-3 (Bulk Pack)	3242Q
AH3243Q-P-A	SIP-3 (Ammo Pack)	3243Q
AH3243Q-P-B	SIP-3 (Bulk Pack)	3243Q
AH3244Q-P-A	SIP-3 (Ammo Pack)	3244Q
AH3244Q-P-B	SIP-3 (Bulk Pack)	3244Q
AH3280Q-P-A	SIP-3 (Ammo Pack)	3280Q
AH3280Q-P-B	SIP-3 (Bulk Pack)	3280Q
AH3281Q-P-A	SIP-3 (Ammo Pack)	3281Q
AH3281Q-P-B	SIP-3 (Bulk Pack)	3281Q
AH3282Q-P-A	SIP-3 (Ammo Pack)	3282Q
AH3282Q-P-B	SIP-3 (Bulk Pack)	3282Q

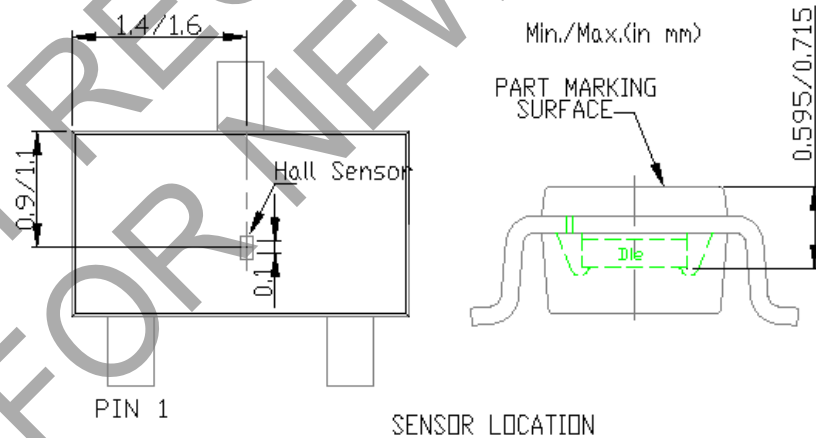
## Package Outline Dimensions (All dimensions in mm.)

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (1) Package Type: SC59 (Type A1)



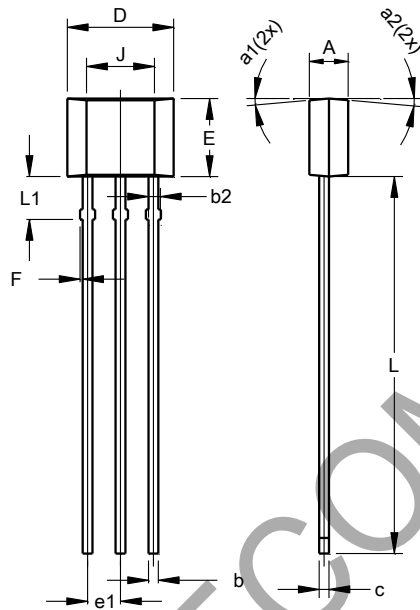
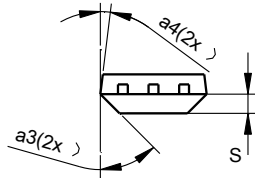
AH32xxQ Hall sensor



## Package Outline Dimensions (continued) (All dimensions in mm.)

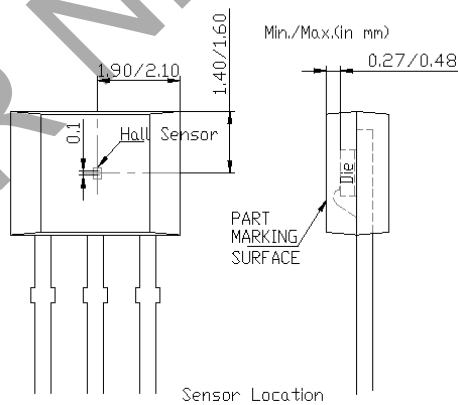
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### (2) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
b	0.33	0.43	0.38
b2	0.40	0.508	0.46
c	0.35	0.41	0.38
D	3.90	4.30	4.10
E	2.80	3.20	3.00
e1	1.24	1.30	1.27
F	0.00	0.20	—
J	2.62 REF		
L	14.00	15.00	14.50
L1	1.55	1.75	1.65
S	0.63	0.84	0.74
a1	—	—	5°
a2	—	—	5°
a3	—	—	45°
a4	—	—	3°
All Dimensions in mm			

AH32xxQ SIP3 Hall sensor

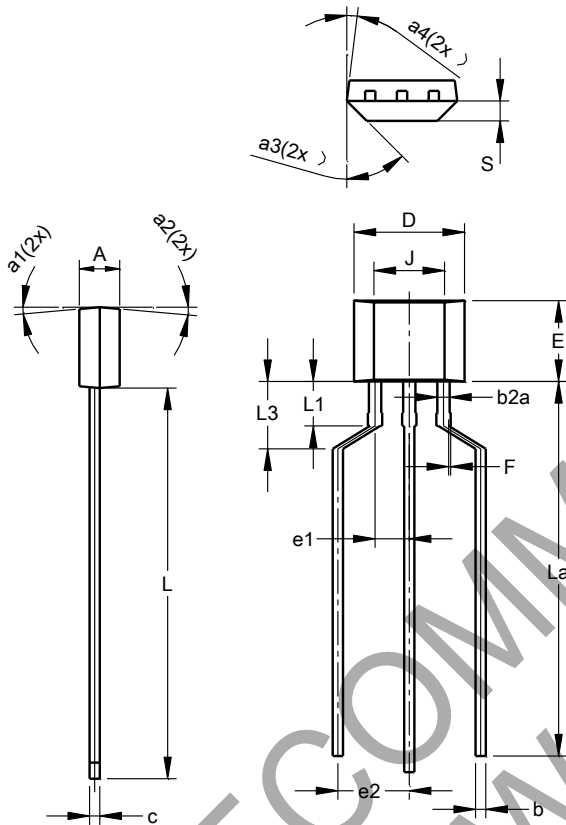




**Package Outline Dimensions** (continued) (All dimensions in mm.)

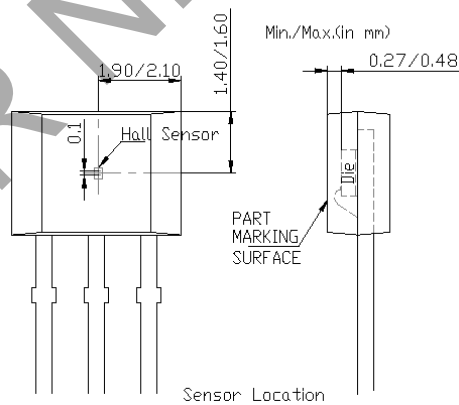
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**(3) Package Type: SIP-3 (Ammo Pack)**



SIP-3 (Ammo Pack)			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
b	0.33	0.43	0.38
b2a	0.40	0.52	0.46
c	0.35	0.41	0.38
D	3.90	4.30	4.10
E	2.80	3.20	3.00
e1	1.24	1.30	1.27
e2	2.40	2.90	2.65
F	0.00	0.20	—
J	2.62 REF		
L	14.00	15.00	14.50
La	12.90	14.90	13.90
L1	1.55	1.75	1.65
L3	2.00	3.00	2.50
S	0.63	0.84	0.74
a1	—	—	5°
a2	—	—	5°
a3	—	—	45°
a4	—	—	3°
All Dimensions in mm			

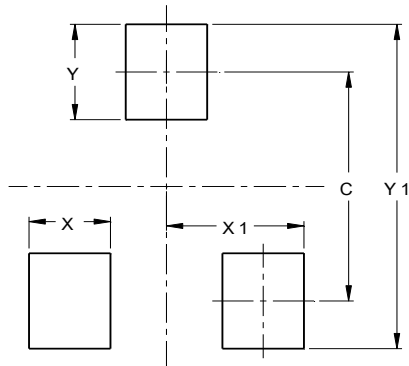
AH32xxQ SIP3 Hall sensor



# Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

(1) Package Type: SC59 (Type A1)



Dimensions	Value (in mm)
C	2.40
X	0.80
X1	1.35
Y	1.00
Y1	3.40

NOT RECOMMENDED  
FOR NEW DESIGN

**IMPORTANT NOTICE**

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
5. Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (<https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/>) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
9. This Notice may be periodically updated with the most recent version available at <https://www.diodes.com/about/company/terms-and-conditions/important-notice>

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries.  
All other trademarks are the property of their respective owners.  
© 2025 Diodes Incorporated. All Rights Reserved.

[www.diodes.com](http://www.diodes.com)